Thick Film Hybrid IC

STK4044XI



AF Power Amplifier (Split Power Supply) (100 W min, THD = 0.008 %)

Features

- · Compact packaging supports slimmer set designs
- Series designed from 50 up to 150 W and pincompatibility
- Simpler heat sink design facilitates thermal design of slim stereo sets

• Current mirror circuit, cascade circuit and purecomplimentary circuit application reduce distortion to 0.008 %

• Supports addition of electronic circuits for thermal shutdown and load-short protection circuit as well as pop noise muting which occurs when the power supply switch is turned on and off.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		± 74	V
Thermal resistance	өј-с		1.2	°C/W
Junction temperature	Tj		150	°C
Operating substrate temperature	Tc		125	°C
Storage temperature	Tstg		-30 to +125	°C
Permissible load short time	t _s *1	$V_{CC} = \pm 51 \text{ V}, \text{ R}_{L} = 8 \Omega, \text{ f} = 50 \text{ Hz}, \text{ P}_{O} = 100 \text{ W}$	1	s

Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		± 51	V
Load resistance	RL		8	Ω

Operating Characteristics at Ta = 25°C, V_{CC} = ± 51 V, R_L = 8 Ω , VG = 40 dB, Rg = 600 Ω , 100 kHz LPF ON, R_L (noninductive)

Parameter	Symbol	Conditions	Ratings			
			min	typ	max	Unit
Quiescent current	Icco	V _{CC} = ± 61.5 V	15		120	mA
Output power	PO	THD = 0.008 %, f = 20 Hz to 20 kHz	100			W
Total harmonic distortion	THD	P _O = 1.0 W, f = 1 kHz			0.008	%
Frequency response	fL, fH	$P_0 = 1.0 \text{ W}, \frac{+0}{-3} \text{ dB}$		20 to 50k		Hz
Input resistance	r _i	P _O = 1.0 W, f = 1 kHz		55		kΩ
Output noise voltage	V _{NO} ^{*2}	$V_{CC} = \pm 61.5 \text{ V}, \text{ Rg} = 10 \text{ k}\Omega$			1.2	mVrms
Neutral voltage	V _N	V _{CC} = ± 61.5 V	-70	0	+ 70	mV

Note: Use rated power supply for test unless otherwise specified.

*1 When measuring permissible load short time and output noise voltage use transformer power supply indicated next page.

*2 Output noise voltage represents the peak value on the rms scale (VTVM). The noise voltage waveform does not include the pulse noise.

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Package Dimensions

unit: mm





Sample Application Circuit: 100W min Single Channel AF Power Amplifier





Sample Printed Circuit Pattern for Application Circuit (Copper-foiled side)

Description of External Parts

Unit (resistance: Ω, capacitance: F)

- R_1, C_1 : Input filter circuit
 - Reduces high-frequency noise.
- C₂ : Input coupling capacitor
 - DC current suppression. A reduction in reactance is effective because of increases in capacitor reactance at low frequencies and 1/f noise dependence on signal source resistance which result in output noise worsening.
- R₂ : Input bias resistor
 - Biases the input pin to zero.
 - Effects V_N stability (refer to NF circuit).
 - Due to differential input, input resistance is more or less determined by this resistance value.
- R_4, R_5 : NFB circuit (AC NF circuit). Use of resistor with 1% error is suggested.
- $C_{3}(R_{2})$



• VG settings are obtained using R_4 and R_5 according to the following equation:

$$\log 20 \cdot \frac{R_5}{R_4}$$
 40 dB is recommended.

• Low-frequency cutoff frequency settings are obtained using R_4 and C_3 according to the following equation:

$$f_{L} = \frac{1}{2\pi \cdot R_{4} \cdot C_{3}} \quad [Hz]$$

When changing the VG setting, you should change R_4 which requires a recheck of the low cutoff frequency setting. When the VG setting is changed using R_5 , the setting should ensure R_2 equals R_5 so that V_N balance stability is maintained. If the resistor value is increased more than the existing value, V_N balance may be disturbed and result in deterioration of V_N temperature characteristics.

R₃ : Differential constant-current bias resistor

- R₆, R₇ : For oscillation suppression and phase compensation applications (For use with differential stage applications)
- R₇, C₄ : For oscillation suppression and phase compensation applications (A Mylar capacitor is recommended for C₄ for use with output stage applications)

r C₉: Negative (–) power

- C₈ : For oscillation suppression and phase compensation applications (Oscillation suppression before power step clip)
- C₅ : For oscillation suppression and distortion improvement applications
- R_8, C_{10} : Ripple filter circuit on positive (+) side.
- R_9, C_{13} : Ripple filter circuit on negative (-) side.
- C₁₁, C₁₂ : For oscillation suppression applications

• Used for reducing power supply impedance to stable IC operation and should be connected near the IC pin. We recommend that you use an electrolytic capacitor.

R₁₀ : Output resistor

- Increases load shorting endurance capacity during times of high output.
- R₁₄, L₁ : For oscillation suppression applications Increases oscillation stability against capacitance loads.





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